



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

US Patent

6,872,323 Bi

Grant Date

March 29, 2005

First Inventor

William R. Entley

Filing Date

November 1, 2001

Appl. No.

10/003,908

Confirmation No.

7739

Title:

In Situ Plasma Process To Remove Fluorine Residues From The

Interior Surfaces Of A CVD Reactor

Docket No.:

NVS013 US

Customer No.:

34036

Santa Clara, California October 31, 2005

COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, VA 22313-1450

REQUEST FOR CERTIFICATE OF CORRECTION

Dear Sir:

Several errors appear in the above-identified patent and need to be corrected as shown in the enclosed "Certificate Of Correction." The errors appear to be mistakes made in the printing of the patent by the U.S. Patent and Trademark Office (USPTO). Hence a certificate of correction is hereby requested, pursuant to 35 USC § 254, 37 CFR 1.322 and MPEP 1480.

Since the mistake was made by the USPTO, no fee should be due. However, if any fee is deemed to be necessary, please charge the fee to the Deposit Account 50-2263 while citing the Attorney Docket No. NVS013 US. Should there be any questions concerning this submission, please call the undersigned at (408) 982-8201.

CERTIFICATE OF MAILING BY "FIRST CLASS"

I hereby certify that this paper or fee is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on the below date.

Attorney for Applicant(s

Date of Signature

Respectfully submitted,

David E. Steuber

Attorney for Applicant(s)

Reg. No. 25,557

Certificate Nov 0 8 2005 Of Correction

NOV U 9 2005

UNITED STATES PATENT AND TRADEMARK OFFICE

CERTIFICATE OF CORRECTION

PATENT NO. : 6,872,323 B1

Page 1 of 1

DATED

: March 29, 2005

INVENTOR(S) : Entley et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

At col. 2, line 48, " C_2P_6 " is deleted and replaced by -- C_2F_6 --.

At col. 5, line 42, " F_2 a" is deleted and replaced by -- F_2 --.

At col. 6, line 31, "Hat" is deleted and replaced by -- H_2O --.

At col. 8, line 13, "farm" is deleted and replaced by --form--.

MAILING ADDRESS OF SENDER:

PATENT NO. <u>6,872,323 B1</u>

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